NSN 5961-01-267-5811

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-267-5811 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Overall Height:** 0.095 inches **Overall Width:** 0.284 inches **Function For Which Designed:** Detector and tunnel diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 forward voltage, dc **Current Rating Per Characteristic:** 3.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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